

# SKKT 172, SKKH 172



**SEMIPACK<sup>®</sup> 2**

## Thyristor / Diode Modules

**SKKH 172**

**SKKT 172**

### Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

### Typical Applications

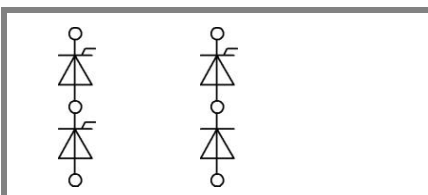
- DC motor control (e.g. for machine tools)
- AC motor soft starters

1) Characteristic values

2) See the assembly instructions

$V_{RSM}$ V	$V_{RRM}, V_{DRM}$ V	$I_{TRMS} = 275$ A (maximum value for continuous operation) $I_{TAV} = 172$ A (sin. 180; $T_c = 86$ °C)	
1500	1400	SKKT 172/14E	
1700	1600	SKKT 172/16E	SKKH 172/16E
1900	1800	SKKT 172/18E	

Symbol	Conditions	Values	Units
$I_{TAV}$	sin. 180; $T_c = 85$ (100) °C;	175 (124)	A
$I_{TSM}$	$T_{vj} = 25$ °C; 10 ms $T_{vj} = 125$ °C; 10 ms	5400 5000	A
$i^2t$	$T_{vj} = 25$ °C; 8,3 ... 10 ms $T_{vj} = 125$ °C; 8,3 ... 10 ms	145000 125000	A <sup>2</sup> s
$V_T$	$T_{vj} = 25$ °C; $I_T = 500$ A	max. 1,41	V
$V_{T(TO)}$	$T_{vj} = 125$ °C	max. 0,83	V
$r_T$	$T_{vj} = 125$ °C	max. 1,3	mΩ
$V_{T(TO)(typ.)}^{1)}$	$T_{vj} = 125$ °C	0,8	V
$r_{T(typ.)}^{1)}$	$T_{vj} = 125$ °C	1,2	mΩ
$I_{DD}, I_{RD}$	$T_{vj} = 125$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 40	mA
$t_{gd}$	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
$t_{gr}$	$V_D = 0,67 * V_{DRM}$	2	μs
$(di/dt)_{cr}$	$T_{vj} = 125$ °C	max. 200	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 125$ °C	max. 1000	V/μs
$t_q$	$T_{vj} = 125$ °C	typ. 175	μs
$I_H$	$T_{vj} = 25$ °C; typ. / max.	150 / 400	mA
$I_L$	$T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.	300 / 1000	mA
$V_{GT}$	$T_{vj} = 25$ °C; d.c.	min. 2	V
$I_{GT}$	$T_{vj} = 25$ °C; d.c.	min. 150	mA
$V_{GD}$	$T_{vj} = 125$ °C; d.c.	max. 0,25	V
$I_{GD}$	$T_{vj} = 125$ °C; d.c.	max. 10	mA
$R_{th(j-c)}$	cont.; per thyristor / per module	0,155 / 0,078	K/W
$R_{th(j-c)}$	sin. 180; per thyristor / per module	0,164 / 0,082	K/W
$R_{th(j-c)}$	rec. 120; per thyristor / per module	0,18 / 0,09	K/W
$R_{th(c-s)}$	per thyristor / per module	0,1 / 0,05	K/W
$T_{vj}$		- 40 ... + 125	°C
$T_{stg}$		- 40 ... + 125	°C
$V_{isol}$	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
$M_s$	to heatsink	$5 \pm 15$ % <sup>2)</sup>	Nm
$M_t$	to terminal	$5 \pm 15$ %	Nm
$a$		$5 * 9,81$	m/s <sup>2</sup>
$m$	approx.	165	g
Case	SKKT SKKH	A 21 A 22	



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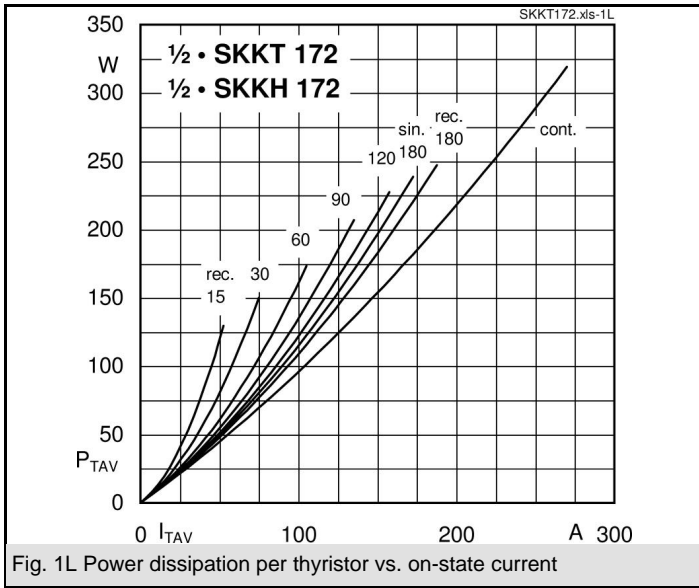


Fig. 1L Power dissipation per thyristor vs. on-state current

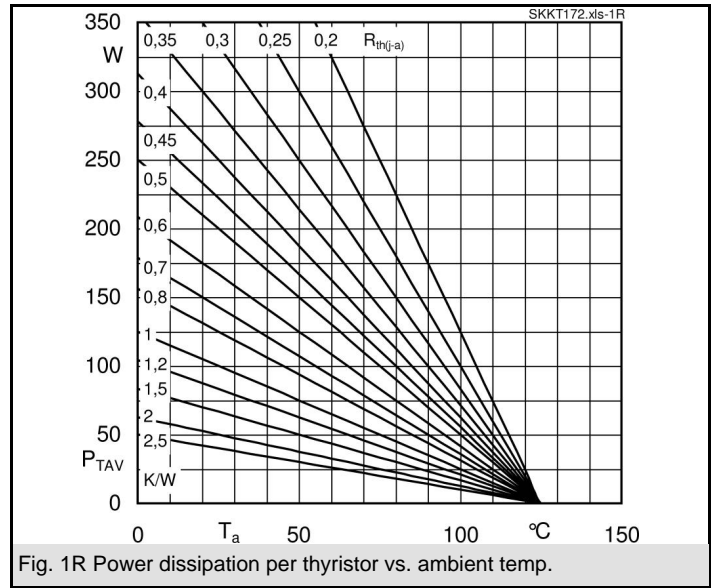


Fig. 1R Power dissipation per thyristor vs. ambient temp.

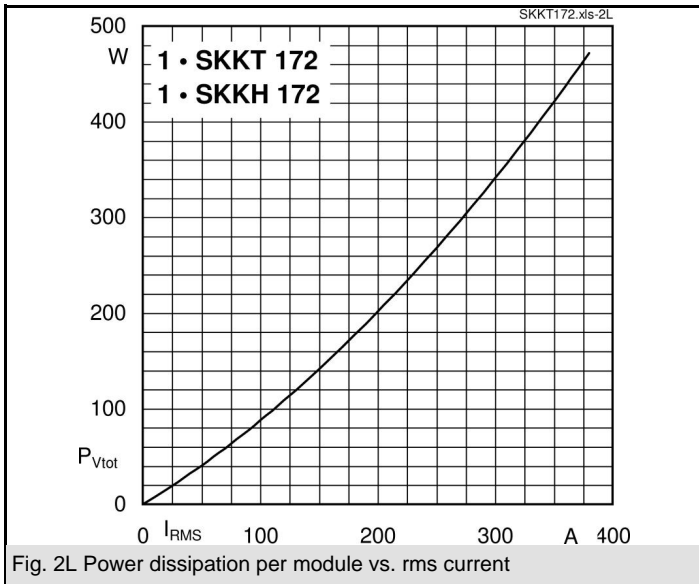


Fig. 2L Power dissipation per module vs. rms current

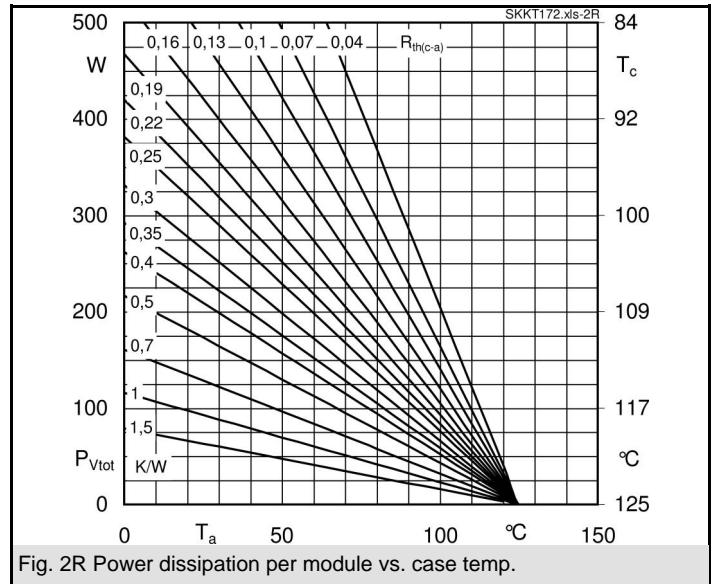


Fig. 2R Power dissipation per module vs. case temp.

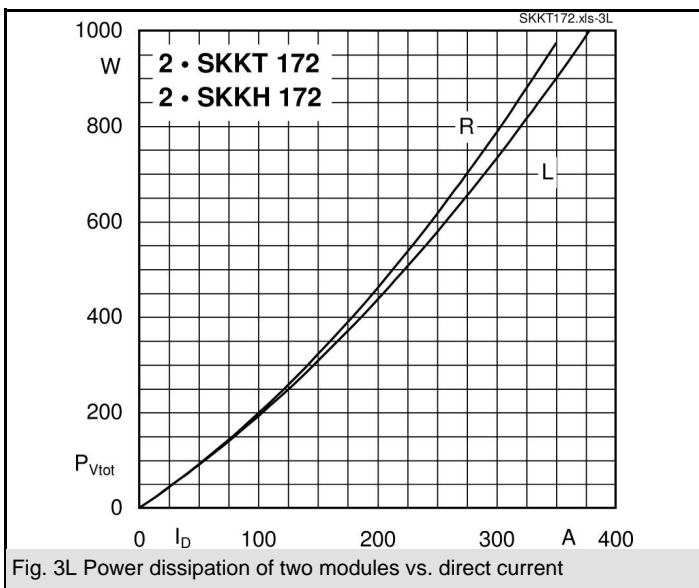


Fig. 3L Power dissipation of two modules vs. direct current

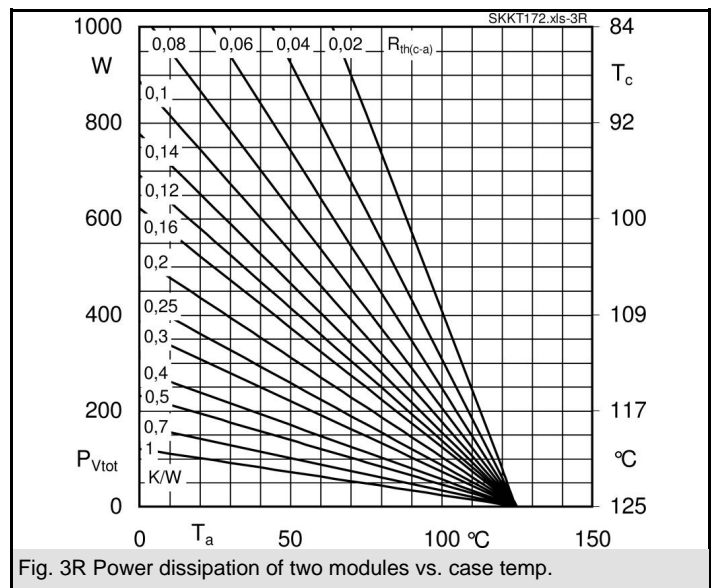
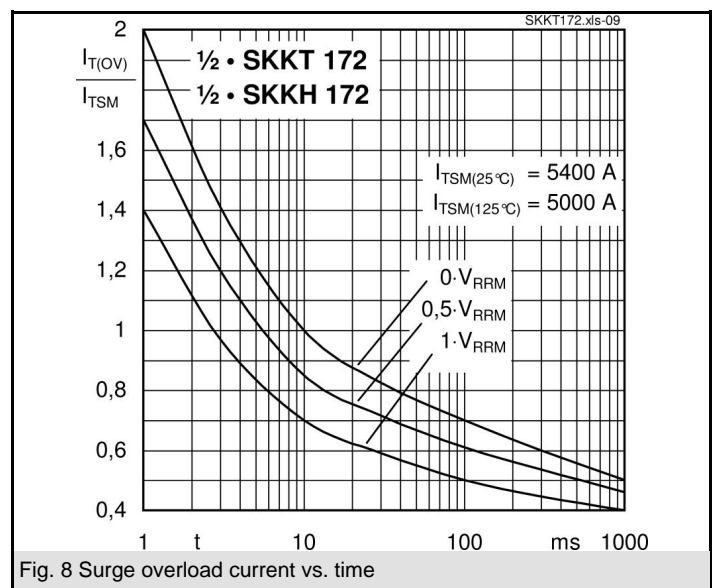
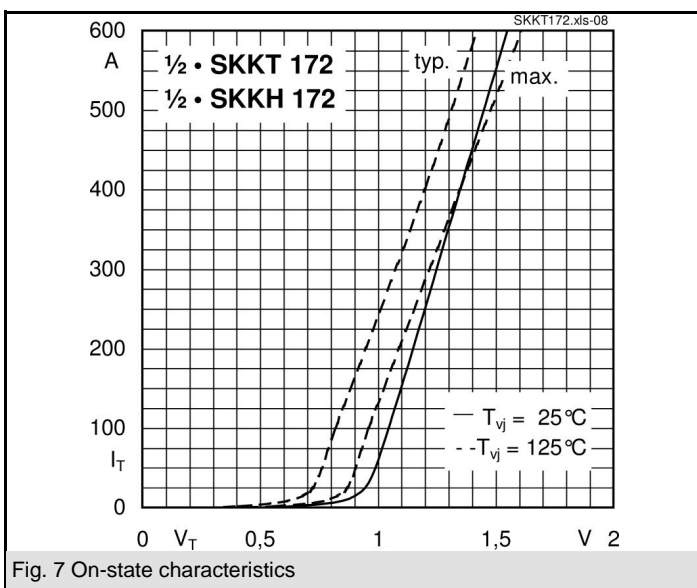
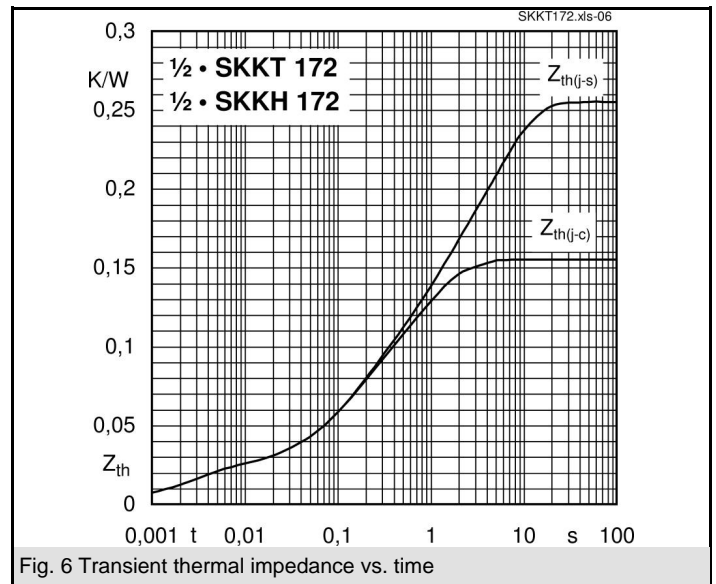
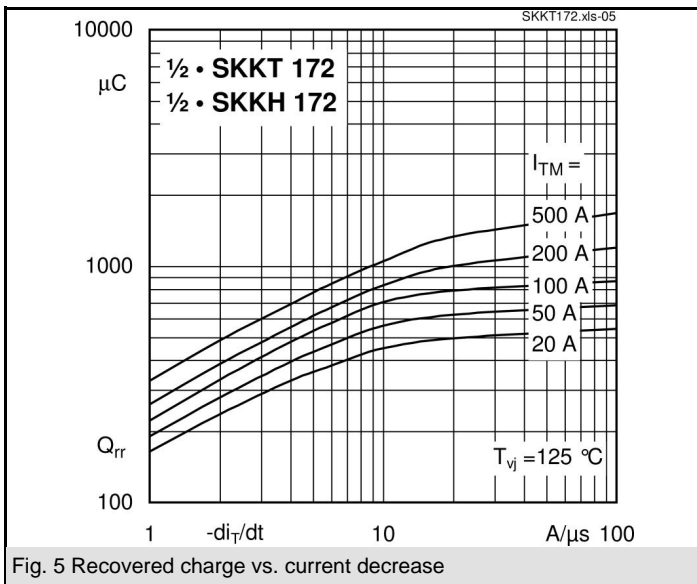
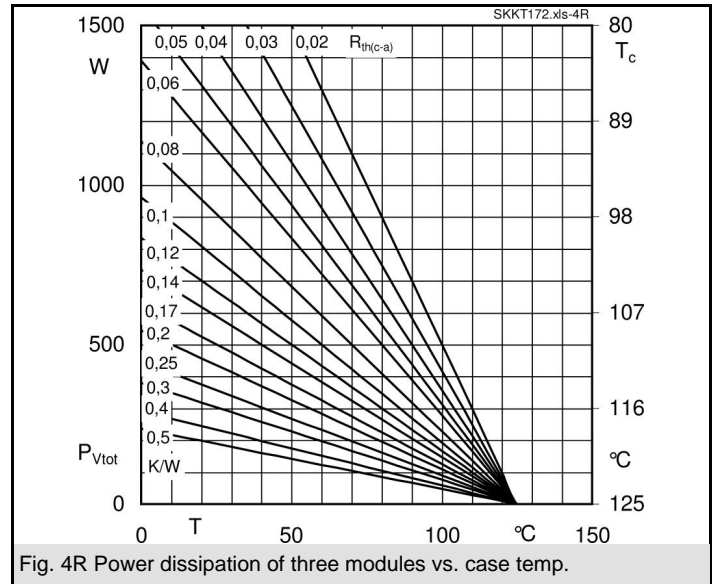
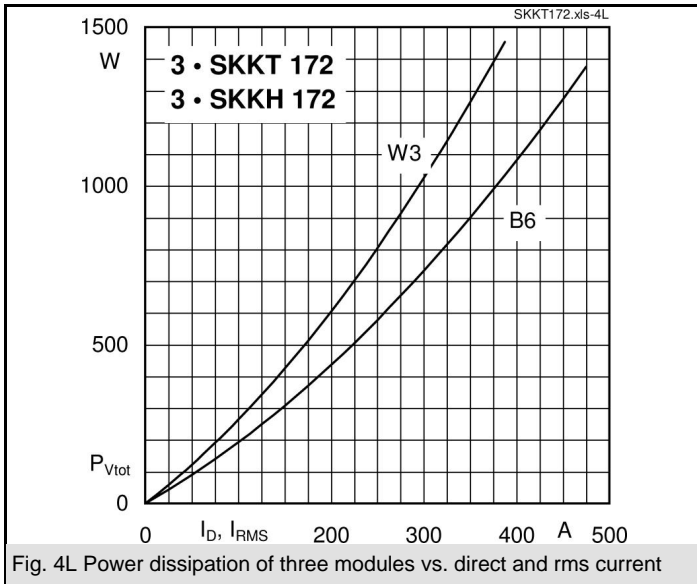
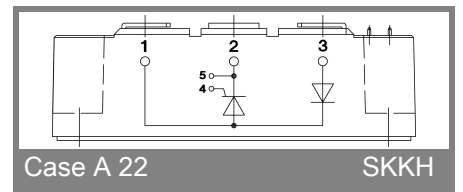
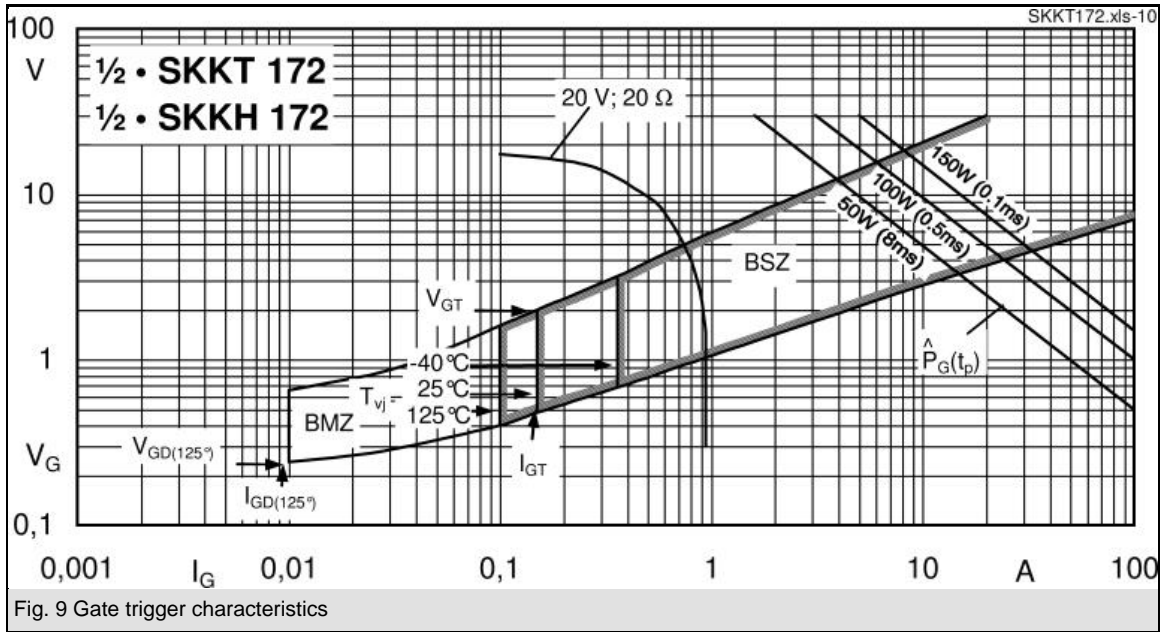


Fig. 3R Power dissipation of two modules vs. case temp.

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